

RoHS

COMPLIANT

Vishay Siliconix

Monolithic Dual SPST CMOS Analog Switch

DESCRIPTION

The DG200B is a dual, single-pole, single-throw analog switch designed to provide general purpose switching of analog signals. This device is ideally suited for designs requiring a wide analog voltage range coupled with low on-resistance.

The DG200B is designed on Vishay Siliconix' improved PLUS-40 CMOS process. An epitaxial layer prevents latchup.

Each switch conducts equally well in both directions when on, and blocks up to 30 V peak-to-peak when off. In the on condition, this bi-directional switch introduces no offset voltage of its own.

FEATURES

- ± 15 V Input Signal Range
- 44 V Maximum Supply Ranges
- On-Resistance: 45 Ω
- TTL and CMOS Compatibility

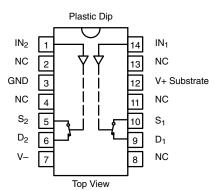
BENEFITS

- Wide Dynamic Range
- Simple Interfacing
- Reduced External Component Count

APPLICATIONS

- Servo Control Switching
- Programmable Gain Amplifiers
- Audio Switching
- Programmable Filters

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



TRUTH TABLE	
Logic	Switch
0	ON
1	OFF

 $\begin{array}{l} Logic "0" \leq 0.8 \ V \\ Logic "1" \geq 2.4 \ V \end{array}$

ORDERING INFORMATION				
Temp Range	Package	Part Number		
- 40 to 85 °C	14-Pin Plastic DIP	DG200BDJ DG200BDJ-E3		

* Pb containing terminations are not RoHS compliant, exemptions may apply



Parameter		Limit	Unit	
V+ to V-		44		
GND to V-		25	v	
Digital Inputs ^a , V _S , V _D		(V-) - 2 V to (V+) + 2 V or 30 mA, whichever occurs first	v	
Current (Any Terminal) Continuous		30		
Current S or D	(Pulsed at 1 ms, 10 % Duty Cycle Max)	100	mA	
Storage Temperature		- 65 to 150	°C	
Power Dissipation (Package) ^b	14-Pin Plastic DIP ^c	470	mW	

a. Signals on S_X , D_X , or IN_X exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings. b. All leads welded or soldered to PC Board.

c. Derate 6.5 mW/°C above 25 °C.

SCHEMATIC DIAGRAM (TYPICAL CHANNEL)

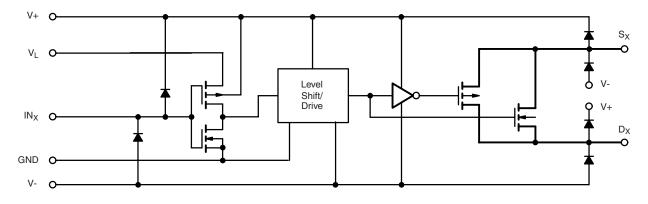


Figure 1.



Parameter		Test Conditions Unless Otherwise Specified V+ = 15 V, V- = - 15 V			Limits - 40 to 85 °C			
	Symbol	V _{IN} = 2.4 V, 0		Temp ^b	Min ^c	Тур ^d	Max ^c	Unit
Analog Switch				•				
Analog Signal Range ^e	V _{ANALOG}			Full	- 15		15	V
Drain-Source On-Resistance	r _{DS(on)}	$V_D = \pm 10$ V, $I_S =$	$V_{D} = \pm 10 \text{ V}, \text{ I}_{S} = -1 \text{ mA}$			45	85 100	Ω
Source Off Leakage Current	I _{S(off)}	$V_{S} = \pm 14 \text{ V}, V_{D} = \pm 14 \text{ V}$		Room Full	- 2 - 100	± 0.01	2 100	
Drain Off Leakage Current	I _{D(off)}	$V_{D} = \pm 14 \text{ V}, V_{S} = \mp 14 \text{ V}$		Room Full	- 2 - 100	± 0.01	2 100	nA
Channel On Leakage Current ^f	I _{D(on)}	$V_{S} = V_{D} = \pm 14 V$		Room Full	- 2 - 200	± 0.1	2 200	1
Digital Control				•		•		
Input Current with Input Voltage High	luu.	V _{IN} = 2.4 V	V _{IN} = 2.4 V		- 0.5 - 1	0.0009		
	V _{IN} = 15 V		Room Full		0.005	0.5 1	μA	
Input Current with Input Voltage Low	I _{INL}	V _{IN} = 0 V		Room Full	- 0.5 - 1	- 0.0015		
Dynamic Characteristics				•				
Turn-On Time	t _{ON}	See Switching Time Test Circuit		Room		300	1000	
Turn-Off Time	t _{OFF}			Room		200	425	ns
Charge Injection	Q	$C_{L} = 1000 \text{ pF}, \text{ R}_{g} = 0 \Omega, \text{ V}_{g} = 0 \text{ V}$		Room		1		pC
Source Off Capacitance	C _{S(off)}	f = 140 kHz	V _S = 0 V	Room		5		
Drain Off Capacitance	C _{D(off)}	V _{IN} = 5 V	$V_D = 0 V$	Room		5		pF
Channel-On Capacitance	C _{D(on)} + C _{S(on)}	$V_{S} = V_{D} = 0 \text{ V}, V_{IN} = 0 \text{ V}$		Room		16		יש
Off Isolation	OIRR	V_{IN} = 5 V, R_L = 75 Ω V_S = 2 V, f = 1 MHz		Room		90		dB
Crosstalk (Channel-to-Channel)	X _{TALK}			Room		95		
Power Supplies								
Positive Supply Current	l+	Both Channels On or Off V _{IN} = 0 V and 5.0 V		Room			50	
Negative Supply Current	-			Room	- 10			μA

Notes:

a. Refer to PROCESS OPTION FLOWCHART.

b. Room = 25 °C, Full = as determined by the operating temperature suffix.

c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

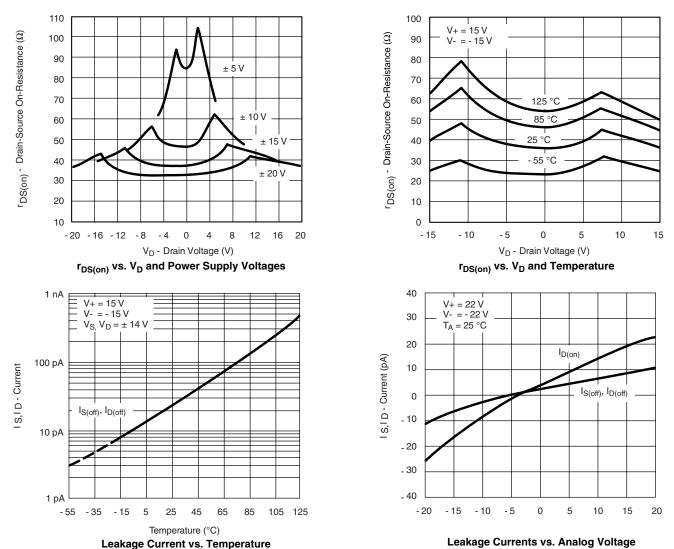
d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.

e. Guaranteed by design, not subject to production test.

f. V_{IN} = input voltage to perform proper function.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

TEST CIRCUITS

V_O is the steady state output with switch on. Feedthrough via gate capacitance may result in spikes at leading and trailing edge of output waveform.

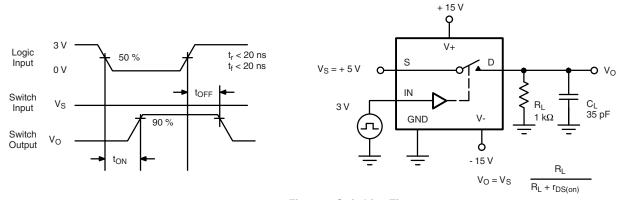
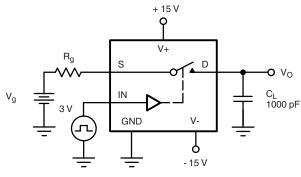


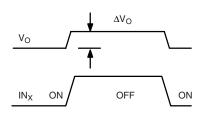
Figure 2. Switching Time



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TEST CIRCUITS





 ΔV_O = measured voltage error due to charge injection The charge injection in coulombs is ΔQ = C $_L$ x ΔV_O

Figure 3. Charge Injection

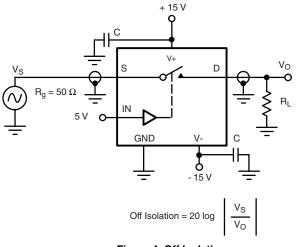


Figure 4. Off Isolation

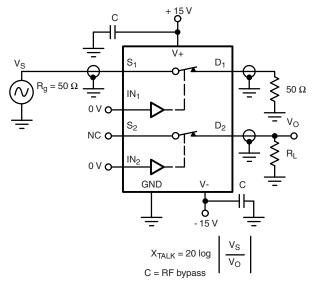


Figure 5. Channel-to-Channel Crosstalk

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